

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Wang et al.

Attorney Docket No.: NOVL085/

NVLS-2875

Application No.: 10/785,235

Examiner: UNASSIGNED

Filed: February 23, 2004

Group: 2812

Title: PLASMA DETEMPLATING AND

SILANOL CAPPING OF POROUS

DIELECTRIC FILMS

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first-class mail on March 24, 2005 in an envelope addressed to the Commissioner for Patents, P.O. Box 1450 Alexandria, VA 22313 1450.

Signed: ___

Joyce L. Ferreira

INFORMATION DISCLOSURE STATEMENT 37 CFR §§1.56 AND 1.97(b)

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

The references listed in the attached PTO Form 1449, copies of which are attached, may be material to examination of the above-identified patent application. Applicants submit these references in compliance with their duty of disclosure pursuant to 37 CFR §§1.56 and 1.97. The Examiner is requested to make these references of official record in this application.

This Information Disclosure Statement is not to be construed as a representation that a search has been made, that additional information material to the examination of this application does not exist, or that these references indeed constitute prior art.

This Information Disclosure Statement is: (i) filed within three (3) months of the filing date of the above-referenced application, (ii) believed to be filed before the mailing date of a first Office Action on the merits, or (iii) believed to be filed before the mailing of a first Office Action after the filing of a Request for Continued Examination under §1.114. Accordingly, it is believed that no fees are due in connection with the filing of this Information Disclosure Statement. However, if it is determined that any fees are due, the Commissioner is hereby authorized to charge such fees to Deposit Account 500388 (Order No. NOVLP085).

Respectfully submitted,

BEYER WEAVER & THOMAS, LLP

Jeffrey K. Weaver

Registration No. 31,314

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Information Disclosure
Statement By Applicant

(Use Several Sheets if Necessary)

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Atty Docket No. Application No.:
NOVL085/NVLS-2875 10/785,235

Applicant:
Wang et al.
Filing Date Group
February 23, 2004 2812

U.S. Patent Documents

Examiner						Sub-	Filing
Initial	No.	Patent No.	Date	Patentee	Class	class	Date
	A1	6,391,932	05/21/02	Gore et al.			08/08/00
	A2	5,789,027	08/04/98	Watkins et al.			11/12/96
	A3	5,700,844	12/23/97	Hedrick et al.			04/09/96
	A4	20030157248	08/21/03	Watkins et al.			11/21/02
	A5	20020123240	09/05/02	Gallagher et al.			11/30/01
	A6	20040096672	05/20/04	Lukas et al.			11/14/02
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	A9						
,	A10						
	A11						

Foreign Patent or Published Foreign Patent Application

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Examiner		Document	Publication	Country or		Sub-	Trans	lation
Initial	No.	No.	Date	Patent Office	Class	class	Yes	No
	B1							
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Other Documents

Examiner					
Initial	No. Author, Title, Date, Place (e.g. Journal) of Publication				
	C1	Humayun et al., "Method For Forming Porous Films By Porogen Removal Combined With In Situ Modification", U.S. Patent No. 10/404,693, filed March 31, 2003, Office Action dated March 15, 2005			
Examiner	<u> </u>	Date Considered			

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Application/Control No. 10/404,693 Application/Control No. 10/404,693 Applicant(s)/Patent Under Reexamination HUMAYUN ET AL. Examiner Brian K Talbot Page 1 of 1

U.S. PATENT DOCUMENTS

		<i>K</i> 7			
77	DEMA	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	Α	US-2003/0157248	08-2003	Watkins et al.	427/256
	В	US-6,391,932	05-2002	Gore et al.	521/61
	С	US-2002/0123240	09-2002	Gallagher et al.	438/781
	D	US-5,700,844	12-1997	Hedrick et al.	521/77
	E	US-5,789,027	08-1998	Watkins et al.	427/250
	F	US-6,444,715	09-2002	Mukherjee et al.	521/64
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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification	
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
*	U	Cho et al., "Plasma treatments of molecularly templated nanoporous silica films", Electrochemical and Solid State Letters, 4(4) G35-G38 (2001)
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.